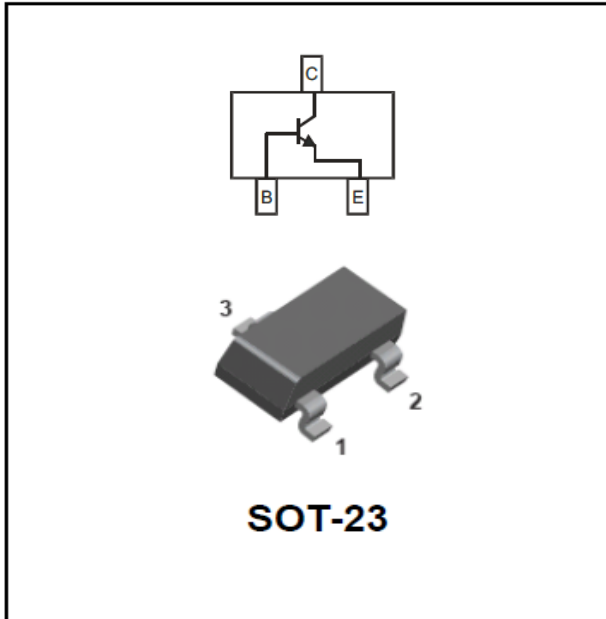


NPN General Purpose Amplifier



Features

- Epoxy meets UL-94 V-0 flammability rating
- Halogen free available upon request by adding suffix "HF"
- Moisture Sensitivity Level 1
- Marking: G1

■ Maximum Ratings (Ta=25°C)

Item	Symbol	Unit	Conditions	Value
Collector-Emitter Voltage*	V_{CE0}	V	$I_C=1.0mA, I_B=0$	160
Collector-Base Voltage	V_{CBO}	V	$I_C=100\mu A, I_E=0$	180
Emitter-Base Voltage	V_{EBO}	V	$I_E=10\mu A, I_C=0$	6.0
Collector Current	I_C	mA		600
Collector Power Dissipation	P_C	mW		300
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	°C/W		417
Operation Junction Temperature	T_j	°C		-55 to +150
Storage Temperature	T_{stg}	°C		-55 to +150

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MMBT5551	F2	Approximate 0.008	3000	30000	120000	7" reel



MMBT5551

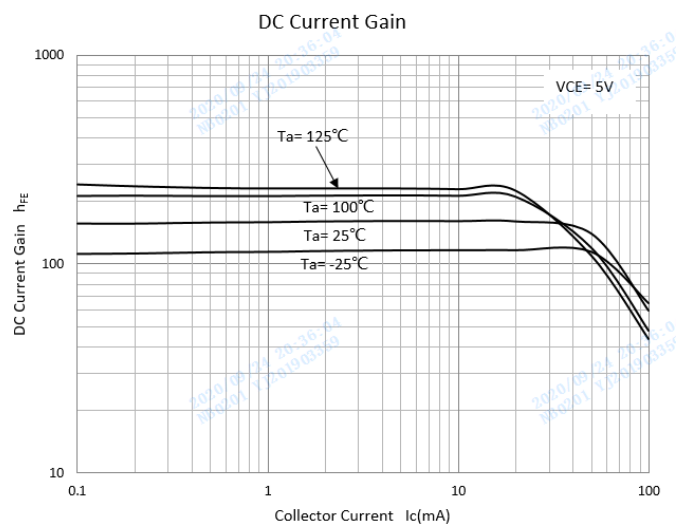
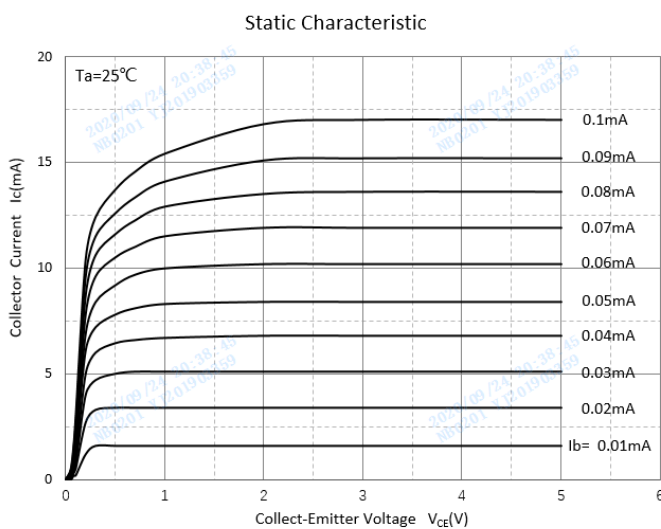
■Electrical Characteristics (T_a=25°C)

Item	Symbol	Unit	Conditions	Min	Max
Collector-Emitter Voltage	V _{CEO}	V	I _C =1.0mA, I _B =0	160	
Collector-Base Voltage	V _{CBO}	V	I _C =100μA, I _E =0	180	
Emitter-Base Voltage	V _{EBO}	V	I _E =10μA, I _C =0	6.0	
Collector-base Cut-off Current	I _{CBO}	nA	V _{CB} =120Vdc		50
Emitter-base Cut-off Current	I _{EBO}	nA	V _{EB} =4.0Vdc		50
DC Current Gain	h _{FE}		I _C =1.0mA V _{CE} =5.0Vdc	80	
			I _C =10mA V _{CE} =5.0Vdc	100	300
			I _C =50mA V _{CE} =5.0Vdc	50	
Collector-Emitter Saturation Voltage	V _{CE(sat)1}	V	I _C =10mA I _B =1.0mA		0.15
	V _{CE(sat)2}	V	I _C =50mA I _B =5.0mA		0.2
Base-Emitter Saturation Voltage	V _{BE(sat)1}	V	I _C =10mA I _B =1.0mA		1
	V _{BE(sat)2}	V	I _C =50mA I _B =5.0mA		1

■Small-signal Characteristics (T_a=25°C)

Item	Symbol	Unit	Conditions	Min	Max
Transition frequency	f _T	MHz	I _C =10mA, V _{CE} =5.0Vdc, f=30MHz	100	300

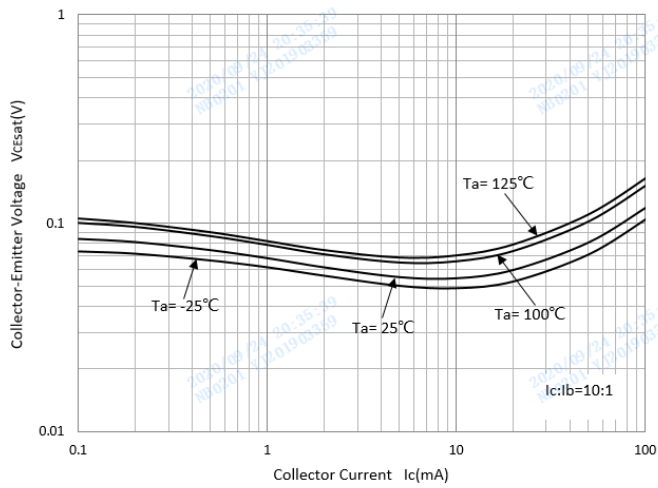
■Characteristics(Typical)



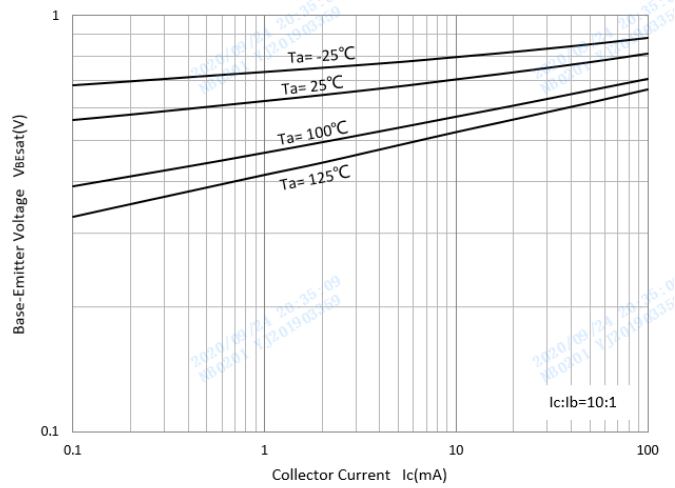


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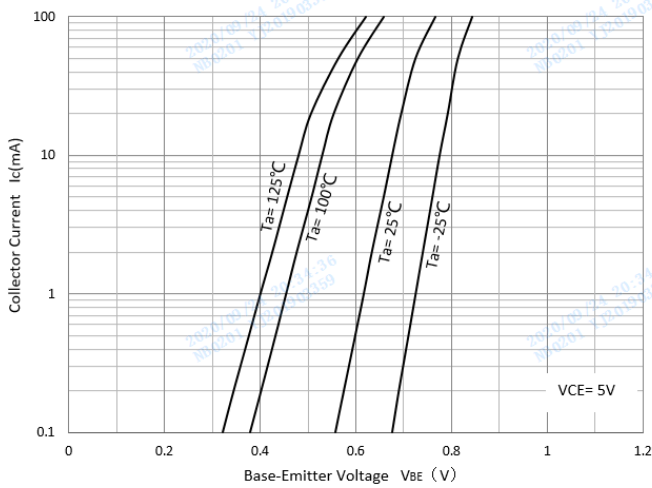
Collector-Emitter Saturation Voltage



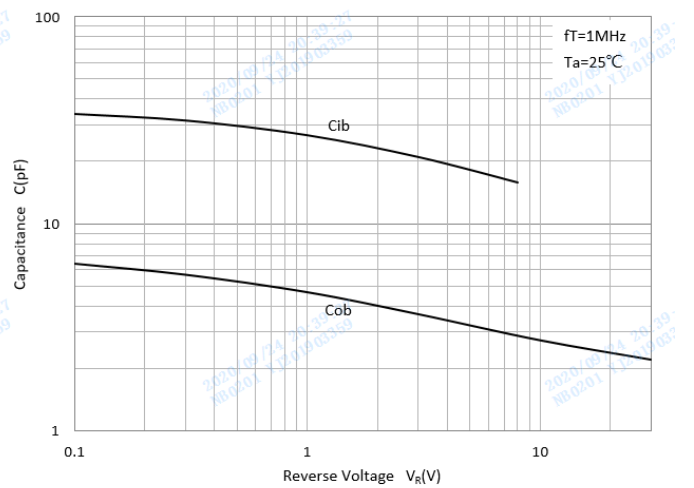
Base-Emitter Saturation Voltage



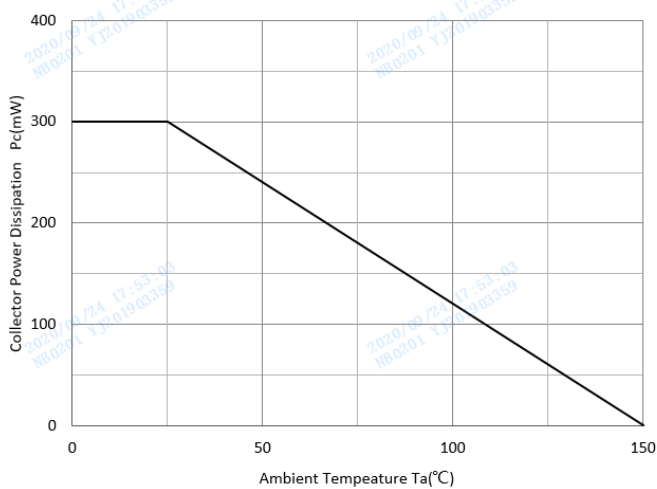
Base-Emitter On Voltage



$C_{ob}/C_{ib} - V_{CB}/V_{EB}$



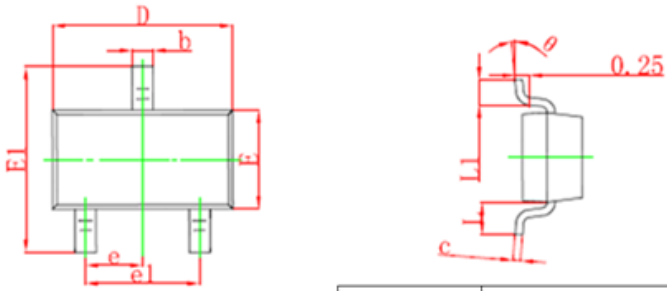
Collector Power Derating Curve





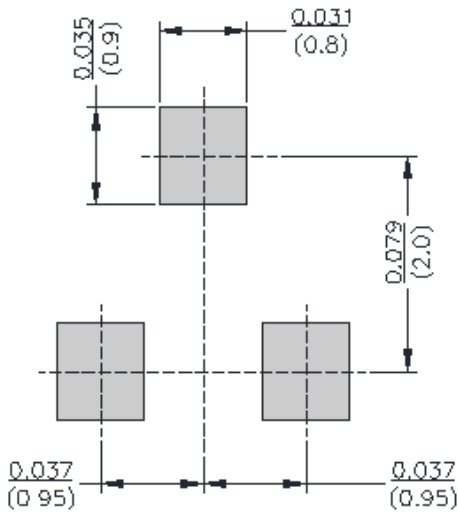
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■SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

■SOT-23 Soldering Footprint





MMBT5551

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